COMPLIANT





### Low-Voltage Single SPDT Analog Switch

### **DESCRIPTION**

The DG2714 is a single-pole/double-throw monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low power, high speed ( $t_{ON}$ : 28 ns,  $t_{OFF}$ : 12 ns), low on-resistance ( $r_{DS(on)}$ : 0.85  $\Omega$ ) and small physical size (SC70), the DG2714 is ideal for portable and battery powered applications requiring high performance and efficient use of board space.

The DG2714 is built on Vishay Siliconix's low voltage submicron CMOS process. An epitaxial layer prevents latchup. Break-before -make is guaranteed for DG2714.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

### **FEATURES**

- Low Voltage Operation (1.6 V to 3.6 V)
- Low On-Resistance  $r_{DS(on)}$ : 0.85  $\Omega$  Typ.
- Fast Switching t<sub>ON</sub>: 28 ns, t<sub>OFF</sub>: 12 ns
- · Low Leakage
- TTL/CMOS Compatible
- 6-Pin SC-70 Package

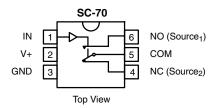
#### **BENEFITS**

- Reduced Power Consumption
- Simple Logic Interface
- High Accuracy
- · Reduce Board Space

### **APPLICATIONS**

- · Cellular Phones
- · Communication Systems
- · Portable Test Equipment
- Battery Operated Systems
- · Sample and Hold Circuits

### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



**Device Marking: E8xx** 

TRUTH TABLE				
Logic	NC	NO		
0	ON	OFF		
1	OFF	ON		

ORDERING INFORMATION				
Temp Range	Package	Part Number		
- 40 to 85 °C	SC70-6	DG2714DL-T1 DG2714DL-T1-E3		

Document Number: 72308 S-70852-Rev. B, 30-Apr-07

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

## Vishay Siliconix



ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Referenced V+ to GND	- 0.3 to + 4	V				
IN, COM, NC, NO <sup>a</sup>	- 0.3 to (V+ + 0.3)	7 v				
Continuous Current (NO, NC and COM	± 200	m A				
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 300	mA mA			
Storage Temperature (D Suffix)	torage Temperature (D Suffix)		°C			
Power Dissipation (Packages) <sup>b</sup>	6-Pin SO70 <sup>c</sup>	250	mW			

### Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC Board. c. Derate 3.1 mW/°C above 70 °C.

SPECIFICATIONS (V-	Symbol	Test Conditions Otherwise Unless Specified $V+=1.8\ V,\pm 10\ \%,\ V_{IN}=0.4\ or\ 1.1\ V^e$		Limits - 40 to 85 °C			
			Temp <sup>a</sup>	Minb	Typ <sup>c</sup>	Max <sup>b</sup>	Unit
Analog Switch			_ · ·		<u> </u>		
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC} V_{COM}$		Full	0		V+	٧
On-Resistance	r <sub>ON</sub>	$V+ = 1.8 \text{ V}, V_{COM} = 0.2 \text{ V}/0.9 \text{ V}$ $I_{NO}, I_{NC} = 10 \text{ mA}$	Room Full <sup>d</sup>		1.8	3.0 4.5	
r <sub>ON</sub> Flatness <sup>d</sup>	r <sub>ON</sub> Flatness	$V+ = 1.8 \text{ V}, V_{COM} = 0 \text{ to } V+, I_{NO}, I_{NC} = 10 \text{ mA}$	Room			2	Ω
r <sub>ON</sub> Match <sup>d</sup>	$\Delta r_{ON}$		Room			0.06	
Switch Off Leakage Current <sup>f</sup>	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	$V_{+} = 2.2 \text{ V}$	Room Full <sup>d</sup>	- 1 - 10		1 10	
	I <sub>COM(off)</sub> V <sub>NO</sub> , V <sub>NC</sub> = 0.2 V/2.0 V, V <sub>COM</sub> = 2.0 V/0.2 V	Room Full <sup>d</sup>	- 1 - 10		1 10	nA	
Channel-On Leakage Current <sup>f</sup>	I <sub>COM(on)</sub>	$V+ = 2.2 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.2 \text{ V}/2.0 \text{ V}$	Room Full <sup>d</sup>	- 1 - 10		1 10	
Digital Control							
Input High Voltage	V <sub>INH</sub>		Full	1.1			V
Input Low Voltage	V <sub>INL</sub>		Full			0.4	
Input Capacitance <sup>d</sup>	C <sub>in</sub>		Full		3.5		pF
Input Current <sup>f</sup>	I <sub>INL</sub> or I <sub>INH</sub>	$V_{IN} = 0$ or $V+$	Full	- 1		1	μΑ
Dynamic Characteristics							
Turn-On Time <sup>d</sup>	t <sub>ON</sub>	VV 45VB 00000 0 055	Room Full <sup>d</sup>		55	75 89	
Turn-Off Time <sup>d</sup>	t <sub>OFF</sub>	$V_{NO}$ or $V_{NC}$ = 1.5 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF Figures 1 and 2	Room Full <sup>d</sup>		19	39 40	ns
Break-Before-Make Time <sup>d</sup>	t <sub>d</sub>		Room	3			
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega, \text{ Figure 3}$	Room		13		рС
Off-Isolation <sup>d</sup>	OIRR	$R_L$ = 50 Ω, $C_L$ = 5 pF, f = 1 MHz	Room		- 64		dB
Crosstalk <sup>d</sup>	X <sub>TALK</sub>		Room		- 64		
NO, NC Off Capacitance <sup>d</sup>	$C_{NO(off)} \ C_{NC(off)}$	V <sub>IN</sub> = 0 or V+, f = 1 MHz	Room		32		pF
Channel-On Capacitance <sup>d</sup>	C <sub>ON</sub>	1	Room		78	İ	'





SPECIFICATIONS (V		Test Conditions		Limits			
Parameter		Otherwise Unless Specified	_		40 to 85 °		Unit
	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.5 \text{ or } 1.5 V^{e}$	Temp <sup>a</sup>	Min <sup>b</sup>	Typ <sup>c</sup>	Max <sup>b</sup>	
Analog Switch	T		1		1	1	
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC}$ $V_{COM}$		Full	0		V+	٧
On-Resistance	r <sub>ON</sub>	$V+ = 2.7 \text{ V}, V_{COM} = 0.2 \text{ V}/1.5 \text{ V}$ $I_{NO}, I_{NC} = 100 \text{ mA}$	Room Full		0.85	1.2 1.3	Ω
r <sub>ON</sub> Flatness	r <sub>ON</sub> Flatness	$V+ = 2.7 \text{ V}, V_{COM} = 0 \text{ to V+}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room			0.2	
r <sub>ON</sub> MatchFlat	∆r <sub>ON</sub>		Room			0.06	
Switch Off Leakage Current	I <sub>NO(off)</sub> I <sub>NC(off)</sub>	$V_{NO}$ , $V_{NC} = 0.3 \text{ V/3 V}$ , $V_{COM} = 3 \text{ V/10.3 V}$	Room Full	- 1 - 10		1 10	nA
Switch Off Leakage Current	I <sub>COM(off)</sub>		Room Full	- 1 - 10		1 10	
Channel-On Leakage Current	I <sub>COM(on)</sub>	$V+ = 3.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.3 \text{ V/3 V}$	Room Full	- 1 - 10		1 10	
Digital Control							
Input High Voltage	V <sub>INH</sub>		Full	1.5			V
Input Low Voltage	V <sub>INL</sub>		Full			0.5	\ \
Input Capacitance <sup>d</sup>	C <sub>in</sub>		Full		3.3		pF
Input Current <sup>f</sup>	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 or V+	Full	- 1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	$V_{NO}$ or $V_{NC}$ = 2.0 V, $R_L$ = 300 $\Omega$ , $C_L$ = 35 pF Figures 1 and 2	Room Full		28	51 55	ns
Turn-Off Time	t <sub>OFF</sub>		Room Full		12	33 34	113
Break-Before-Make Time	t <sub>d</sub>		Room	1			
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	$C_L = 1$ nF, $V_{GEN} = 0$ V, $R_{GEN} = 0$ $\Omega$ , Figure 3	Room		9		рС
Off-Isolation <sup>d</sup>	OIRR	B = 50 0 C = 5 pE f = 1 MHz	Room	_	- 64		4D
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	Room		- 64		dB
NO, NC Off Capacitance <sup>d</sup>	C <sub>NO(off)</sub> C <sub>NC(off)</sub>	V <sub>IN</sub> = 0 or V+, f = 1 MHz	Room		30		pF
Channel-On Capacitance <sup>d</sup>	C <sub>ON</sub>	1	Room		77		
Power Supply							
Power Supply Range	V+			1.5		3.6	V
Power Supply Current	l+	V+ = 3.6 V, V <sub>IN</sub> = 0 or V+			0.01	1.0	μA

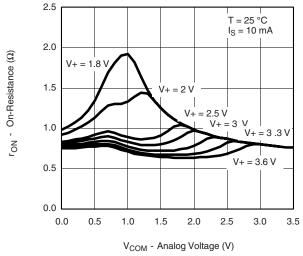
#### Notes:

- a. Room = 25  $^{\circ}$ C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, nor subjected to production test.
- e. V<sub>IN</sub> = input voltage to perform proper function.
- f. Guaranteed by 3 V leakage testing, not production tested.

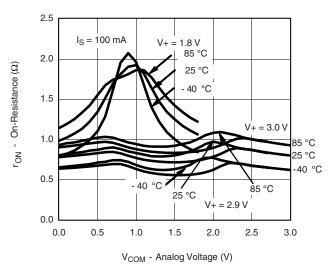
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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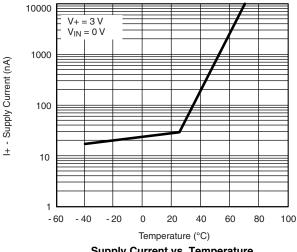
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



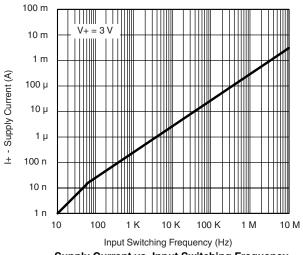
 $r_{ON}$  vs.  $V_{COM}$  and Single Supply Voltage



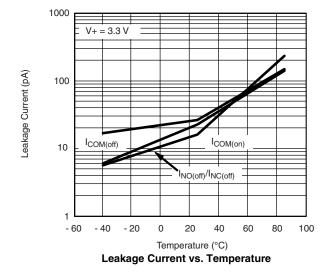
r<sub>ON</sub> vs. Analog Voltage and Temperature

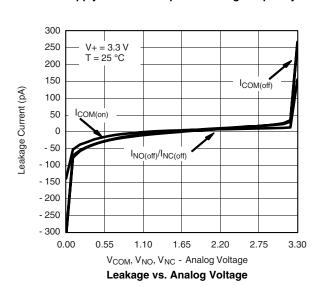


Supply Current vs. Temperature



**Supply Current vs. Input Switching Frequency** 



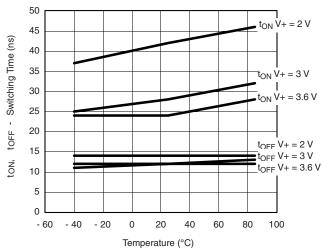




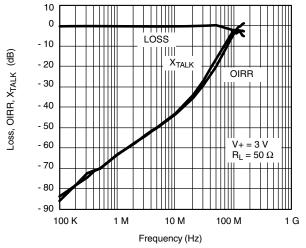




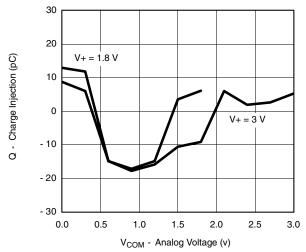
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Charge Injection vs. Analog Voltage

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### **TEST CIRCUITS**

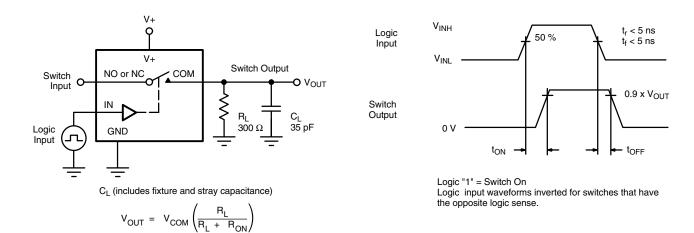


Figure 1. Switching Time

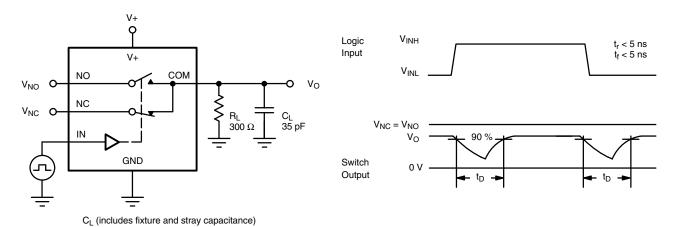


Figure 2. Break-Before-Make Interval

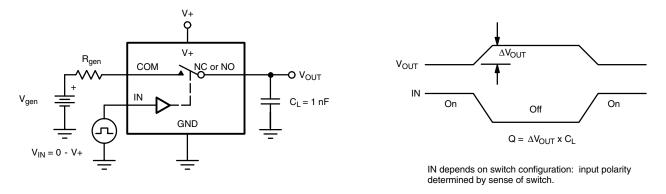


Figure 3. Charge Injection



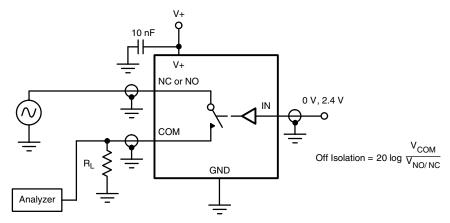


Figure 4. Off-Isolation

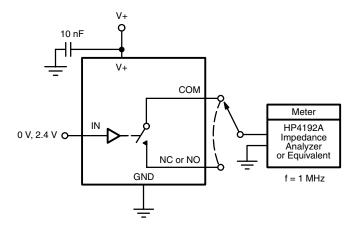


Figure 5. Channel Off/On Capacitance

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Document Number: 91000 Revision: 18-Jul-08

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